

RoHS

COMPLIANT

# **CMOS Analog Switches**

#### **DESCRIPTION**

The DG304B, DG306B and DG307B monolithic CMOS switches were designed for applications in communications, instrumentation and process control. This series is well suited for applications requiring fast switching and nearly flat on-resistance over the entire analog range.

Designed on the Vishay Siliconix PLUS-40 CMOS process to achieve low power consumption and excellent on/off switch performance, these switches are ideal for battery powered applications, without sacrificing switching speed.

Break-before-make switching action is guaranteed, and an epitaxial layer prevents latchup. Single supply operation (for positive switch voltages) is allowed by connecting the V- rail to 0 V.

Each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. These switches are CMOS input compatible.

#### **FEATURES**

- ± 15 V input range
- Fast switching ton: 110 ns

• Low R<sub>DS(on)</sub>: 30 Ω

- · Single supply operation
- · CMOS logic levels
- Micropower: 30 nW

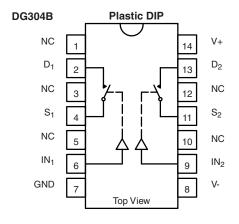
#### **BENEFITS**

- Full rail-to-rail analog signal range
- · Low signal error
- Wide dynamic range
- · Low power dissipation

#### **APPLICATIONS**

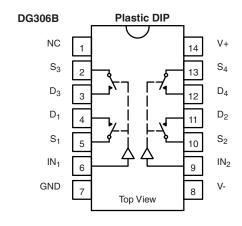
- · Low level switching circuits
- · Programmable gain amplifiers
- · Portable and battery powered systems

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



| TRUTH TABLE |        |  |  |  |
|-------------|--------|--|--|--|
| Logic       | Switch |  |  |  |
| 0           | OFF    |  |  |  |
| 1           | ON     |  |  |  |

Logic "0" ≤ 3.5 V Logic "1" ≥ 11 V



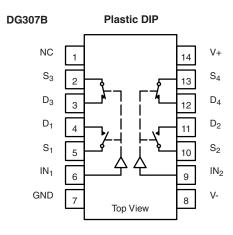
| TRUTH TABLE |        |  |  |  |
|-------------|--------|--|--|--|
| Logic       | Switch |  |  |  |
| 0           | OFF    |  |  |  |
| 1           | ON     |  |  |  |

 $\begin{array}{l} Logic~"0" \leq 3.5~V \\ Logic~"1" \geq 11~V \end{array}$ 

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply.



#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



Four SPST switches per package

| TRUTH TABLE |                                   |              |  |  |
|-------------|-----------------------------------|--------------|--|--|
| Logic       | SW <sub>1</sub> , SW <sub>2</sub> | $SW_3, SW_4$ |  |  |
| 0           | OFF                               | ON           |  |  |
| 1           | ON                                | OFF          |  |  |

Logic "0" ≤ 3.5 V Logic "1" ≥ 11 V

| ORDERING INFORMATION  |                    |          |             |  |  |  |
|---|--------------------|----------|-------------|--|--|--|
| Temp. Range Package Standard Part Number Lead (Pb)-free Part Number |                    |          |             |  |  |  |
| - 40 °C to 85 °C  |                    | DG304BDJ | DG304BDJ-E3 |  |  |  |
|   | 14-Pin Plastic DIP | DG306BDJ | DG306BDJ-E3 |  |  |  |
|   |                    | DG307BDJ | DG307BDJ-E3 |  |  |  |

| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted) |                                 |  |       |  |
|---|---------------------------------|--|-------|--|
| Parameter   |                                 | Limit  | Unit  |  |
| Voltages Referenced V+ to V-  |                                 | 44   |       |  |
| GND   |                                 | 25   | V     |  |
| Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>             |                                 | (V-) - 2 to (V+) + 2<br>or 30 mA, whichever occurs first |       |  |
| Current (Any Terminal)  |                                 | 30   | mA    |  |
| Continuous Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)         |                                 | 100  | ] "'' |  |
| Storage Temperature   |                                 | - 65 to 150  | °C    |  |
| Power Dissipation <sup>b</sup>  | 14-Pin Plastic DIP <sup>c</sup> | 470  | mW    |  |

#### Notes

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 11 mW/°C above 25 °C.



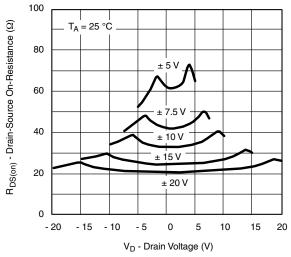
|                                      |                     | Test Conditions Unless Otherwise Specified V+ = 15 V. V- = - 15 V  |           |              | Limits<br>- 40 °C to 85 °C |                   |                   |      |
|--------------------------------------|---------------------|--|-----------|--------------|----------------------------|-------------------|-------------------|------|
| Parameter                            | Symbol              | $V_{IN} = 3.5 \text{ V or}$  |           | Temp.b       | Min. <sup>d</sup>          | Typ. <sup>c</sup> | Max. <sup>d</sup> | Unit |
| Analog Switch                        | · · ·               |  |           |              |                            |                   | L                 |      |
| Analog Signal Range <sup>e</sup>     | V <sub>ANALOG</sub> |  |           | Full         | - 15                       |                   | 15                | V    |
| Drain-Source On-Resistance           | R <sub>DS(on)</sub> | $V_D = \pm 10 \text{ V, I}_S =$                                    | = 10 mA   | Room<br>Full |                            | 30                | 50<br>75          | Ω    |
| Source Off Leakage Current           | I <sub>S(off)</sub> | $V_{S} = \pm 14 \text{ V}, V_{D}$                                  | = + 14 V  | Room<br>Full | - 5<br>- 100               | ± 0.1             | 5<br>100          |      |
| Drain Off Leakage Current            | I <sub>D(off)</sub> | •§ - ± · · •, • <sub>D</sub>                                       | - <b></b> | Room<br>Full | - 5<br>- 100               | ± 0.1             | 5<br>100          | nA   |
| Drain On Leakage Current             | I <sub>D(on)</sub>  | $V_D = V_S = \pm$  | 14 V      | Room<br>Full | - 5<br>- 200               | ± 0.1             | 5<br>200          |      |
| Digital Control                      |                     |  |           |              |                            |                   |                   |      |
| Input Current with                   | rent with           |  | 1         | Room<br>Full | - 1                        | - 0.001           |                   | μА   |
| Input Voltage High                   | I <sub>INH</sub>    | V <sub>IN</sub> = 15 V   |           | Room<br>Full |                            | 0.001             | 1                 |      |
| Input Current with Input Voltage Low | I <sub>INL</sub>    | V <sub>IN</sub> = 0 V  |           | Room<br>Full | - 1                        | - 0.001           |                   |      |
| Dynamic Characteristics              |                     |  |           |              |                            |                   |                   |      |
| Turn-On Time                         | t <sub>ON</sub>     | see figure   | 2         | Room         |                            | 110               |                   |      |
| Turn-Off Time                        | t <sub>OFF</sub>    | see ligure   | 2         | Room         |                            | 70                |                   | ns   |
| Break-Before-Make Time               | t <sub>OPEN</sub>   | DG305A/307A ONLY   | -         | Room         |                            | 50                |                   |      |
| Charge Injection                     | Q                   | $C_L = 1 \text{ nF, } R_{gen} = 0 \Omega$<br>see figure            | 3 -       | Room         |                            | 30                |                   | рС   |
| Source-Off Capacitance               | C <sub>S(off)</sub> |  |           | Room         |                            | 14                |                   |      |
| Drain-Off Capacitance                | C <sub>D(off)</sub> | $V_{S}, V_{D} = 0 V, f =$  | 1 MHz     | Room         |                            | 14                |                   |      |
| Channel-On Capacitance               | C <sub>D(on)</sub>  |  |           | Room         |                            | 40                |                   | pF   |
| Input Capacitance                    | C <sub>IN</sub>     | $f = 1 \text{ MHz}$ $V_{IN} = 0 \text{ V}$ $V_{IN} = 15 \text{ V}$ |           | Room         |                            | 6                 |                   |      |
| mpar Sapasitarios                    | 9114                |  |           | Room         |                            | 7                 |                   |      |
| Off-Isolation                        | OIRR                | $V_{IN} = 0 \text{ V}, R_L = 1 \text{ k}\Omega$                    |           | Room         |                            | 62                |                   | dB   |
| Crosstalk (Channel-to-Channel)       | X <sub>TALK</sub>   | $V_{S} = 1 V_{rms}, f = 500 \text{ kHz}$                           |           | Room         |                            | 74                |                   | GD.  |
| Power Supplies                       |                     |  |           |              |                            |                   |                   |      |
| Positive Supply Current              | l+                  | V <sub>IN</sub> = 15 V or 0 V<br>(all inputs)                      |           | Room<br>Full |                            | 0.001             | 100               | μΑ   |
| Negative Supply Current              | I-                  |  |           | Room<br>Full | - 100                      | - 0.001           |                   | ""   |

#### Notes:

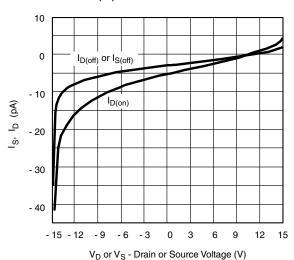
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25  $^{\circ}\text{C},\,\text{Full}$  = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

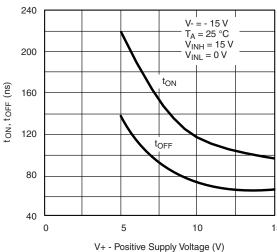
#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



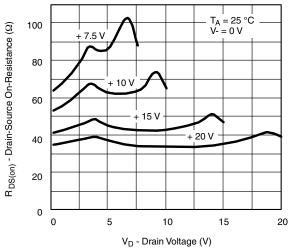
 $R_{DS(on)}$  vs.  $V_D$  and  $\pm$  Power Supply



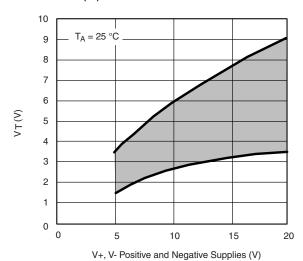
Leakage Currents vs. Analog Voltage



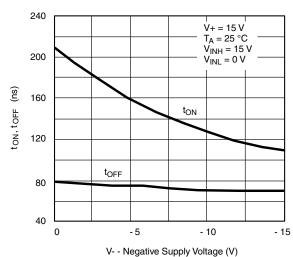
Switching Time vs. Positive Supply Voltage



R<sub>DS(on)</sub> vs. V<sub>D</sub> and + Power Supply Voltage

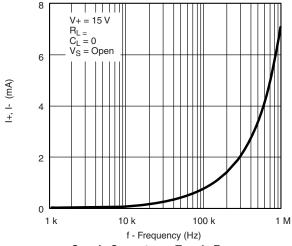


#### Input Switching Threshold vs. V+ and V-**Supply Voltages**



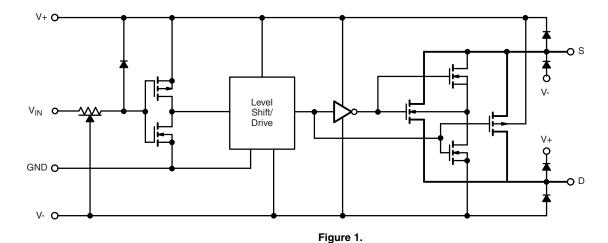


#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Supply Currents vs. Toggle Frequency

### **SCHEMATIC DIAGRAM** (Typical Channel)



#### **TEST CIRCUITS**

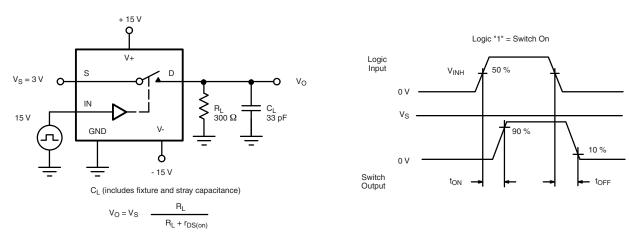
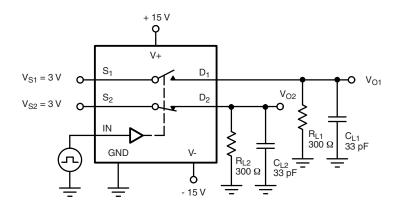
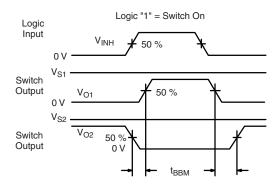


Figure 2. Switching Time

#### **TEST CIRCUITS**

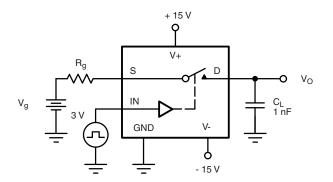






C<sub>L</sub> (includes fixture and stray capacitance)

Figure 3. Break-Before-Make SPDT (DG307B)



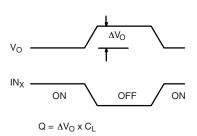


Figure 4. Charge Injection

| APPLICATIONS HINTS <sup>a</sup>         |   |                       |   |  |  |
|---|---|-----------------------|---|--|--|
| V+<br>Positive Supply<br>Voltage<br>(V) | V-<br>Negative Supply<br>Voltage<br>(V) | GND<br>Voltage<br>(V) | V <sub>IN</sub><br>Logic Input Voltage<br>V <sub>INH(min)</sub> /V <sub>INL(max)</sub><br>(V) | V <sub>S</sub> or V <sub>D</sub><br>Analog Voltage<br>Range<br>(V) |  |
| 15                                      | - 15                                    | 0                     | 11/3.5  | - 15 to 15   |  |
| 20                                      | - 20                                    | 0                     | 11/3.5  | - 20 to 20   |  |
| 15                                      | 0                                       | 0                     | 11/3.5  | 0 to 15  |  |

Notes:

a. Application hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

#### **APPLICATIONS**

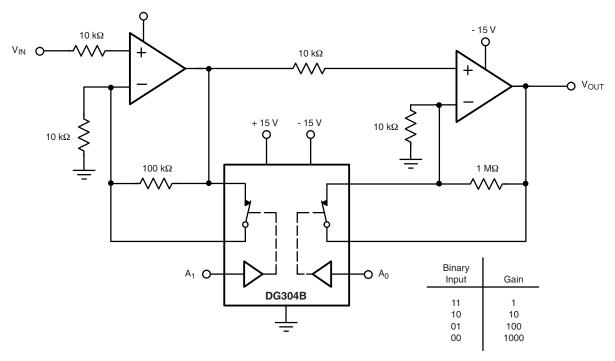


Figure 5. Low Power Binary to 10<sup>n</sup> Gain Low Frequency Amplifier

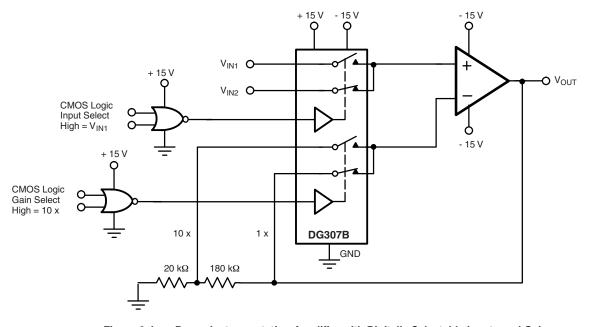
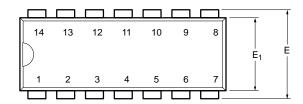


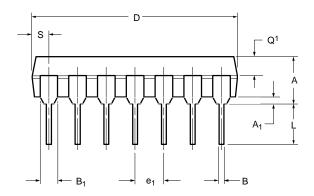
Figure 6. Low Power Instrumentation Amplifier with Digitally Selectable Inputs and Gain

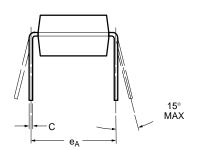
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PDIP: 14-LEAD







|   | MILLIMETERS |       | INC   | HES   |  |
|---|-------------|-------|-------|-------|--|
| Dim   | Min         | Max   | Min   | Max   |  |
| Α   | 3.81        | 5.08  | 0.150 | 0.200 |  |
| A <sub>1</sub>                              | 0.38        | 1.27  | 0.015 | 0.050 |  |
| В   | 0.38        | 0.51  | 0.015 | 0.020 |  |
| B <sub>1</sub>                              | 0.89        | 1.65  | 0.035 | 0.065 |  |
| С   | 0.20        | 0.30  | 0.008 | 0.012 |  |
| D   | 17.27       | 19.30 | 0.680 | 0.760 |  |
| E   | 7.62        | 8.26  | 0.300 | 0.325 |  |
| E <sub>1</sub>                              | 5.59        | 7.11  | 0.220 | 0.280 |  |
| e <sub>1</sub>                              | 2.29        | 2.79  | 0.090 | 0.110 |  |
| e <sub>A</sub>                              | 7.37        | 7.87  | 0.290 | 0.310 |  |
| L   | 2.79        | 3.81  | 0.110 | 0.150 |  |
| Q <sub>1</sub>                              | 1.27        | 2.03  | 0.050 | 0.080 |  |
| S   | 1.02        | 2.03  | 0.040 | 0.080 |  |
| ECN: S-03946—Rev. C, 09-Jul-01<br>DWG: 5481 |             |       |       |       |  |

Document Number: 71260 www.vishay.com 05-Jul-01 www.vishay.com



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Revision: 02-Oct-12 Document Number: 91000